



A5A:670.XX

VOLTAGE RATINGS

Part Number	V_{RRM}, V_R (V) Max. rep. peak reverse voltage		V_{RSM}, V_R (V) Max. non- rep. peak reverse voltage
	$T_J = 0$ to 180°C	$T_J = -40$ to 0°C	$T_J = 25$ to 180°C
	A5A:670.02	200	200
A5A:670.04	400	400	500
A5A:670.06	600	600	700
A5A:670.08	800	800	900
A5A:670.10	1000	1000	1100
A5A:670.12	1200	1200	1300

MAXIMUM ALLOWABLE RATINGS

PARAMETER	VALUE	UNITS	NOTES
T_J Junction Temperature	-40 to 180	$^\circ\text{C}$	-
T_{stg} Storage Temperature	-40 to 180	$^\circ\text{C}$	-
$I_{F(AV)}$ Max. Av. current @ Max. T_C	550	A	180° half sine wave
	125	$^\circ\text{C}$	
$I_{F(RMS)}$ Nom. RMS current	1060	A	-
I_{FSM} Max. Peak non-rep. surge current	7.65	kA	50 Hz half cycle sine wave Initial $T_J = 180^\circ\text{C}$, rated V_{RRM} applied after surge.
	8.00		60 Hz half cycle sine wave
	9.10		50 Hz half cycle sine wave Initial $T_J = 180^\circ\text{C}$, no voltage applied after surge.
	9.50		60 Hz half cycle sine wave
I^2t Max. I^2t capability	267	kA^2s	$t = 10\text{ms}$ Initial $T_J = 180^\circ\text{C}$, rated V_{RRM} applied after surge.
	292		$t = 8.3\text{ms}$
	378		$t = 10\text{ms}$ Initial $T_J = 180^\circ\text{C}$, no voltage applied after surge.
	414		$t = 8.3\text{ms}$
$I^2t^{1/2}$ Max. $I^2t^{1/2}$ capability	4140	$\text{kA}^2\text{s}^{1/2}$	Initial $T_J = 180^\circ\text{C}$, no voltage applied after surge. for time $t_x = I^2t^{1/2} * t_x^{1/2}$. ($0.1 < t_x < 10\text{ms}$). $\hat{I}t$
F Mounting Force	450	N.m	-



A5A:670.XX

CHARACTERISTICS

PARAMETER	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
V_{FM} Peak forward voltage	---	1.50	1.67	V	Initial $T_J = 25^\circ\text{C}$, 50-60Hz half sine, $I_{peak} = 1728\text{A}$.
$V_{F(TO)1}$ Low-level threshold	---	---	0.782	V	$T_J = 180^\circ\text{C}$
$V_{F(TO)2}$ High-level threshold	---	---	0.859		Av. power = $V_{F(TO)} * I_{F(AV)} + r_F * [I_{F(RMS)}]^2$
r_{F1} Low-level resistance	---	---	0.541	m	Use low values for $I_{FM} < I_{F(AV)}$
r_{F2} High-level resistance	---	---	0.470		
I_{RM} Peak reverse current	---	13	30	mA	$T_J = 180^\circ\text{C}$. Max. Rated VRRM
R_{thJC} Thermal resistance, junction-to-case	---	---	0.080	$^\circ\text{C/W}$	DC operation, double side
	---	---	0.092	$^\circ\text{C/W}$	180° sine wave, double side
	---	---	0.094	$^\circ\text{C/W}$	120° rectangular wave, duple side
R_{thCS} Thermal resistance, case-to-sink	---	---	0.03	$^\circ\text{C/W}$	Mtg. Surface smooth, flat and greased.
wt Weight	---	57(2.0)	---	g(oz.)	---
Case Style	DO-200AA			JEDEC	---

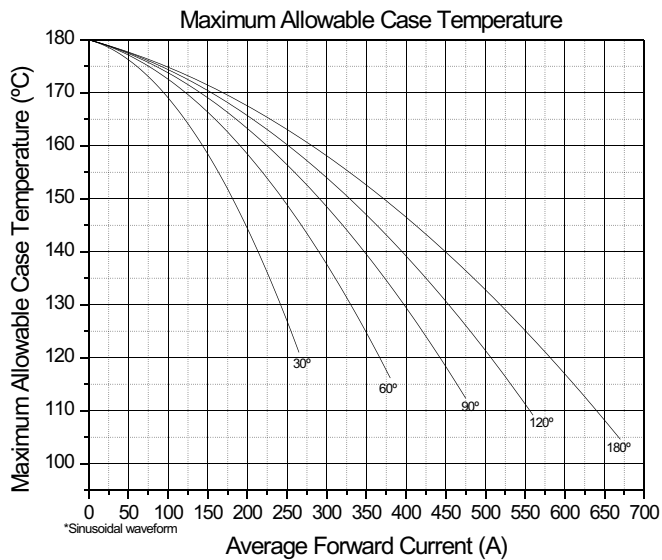


Fig. 1 - Current Ratings Characteristics

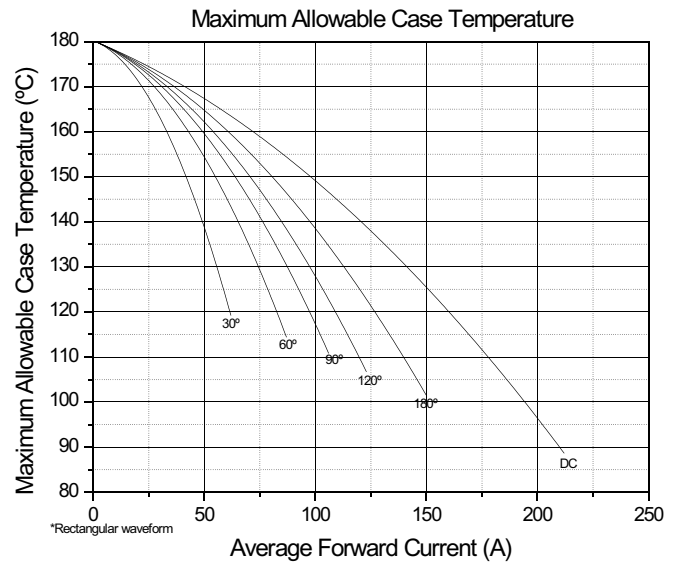


Fig. 2 - Current Ratings Characteristics



A5A:670.XX

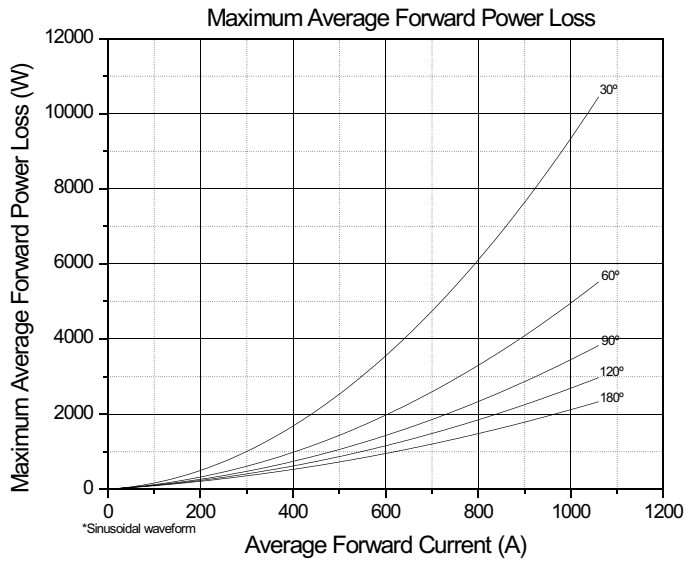


Fig. 3 - On-State Power Loss Characteristics

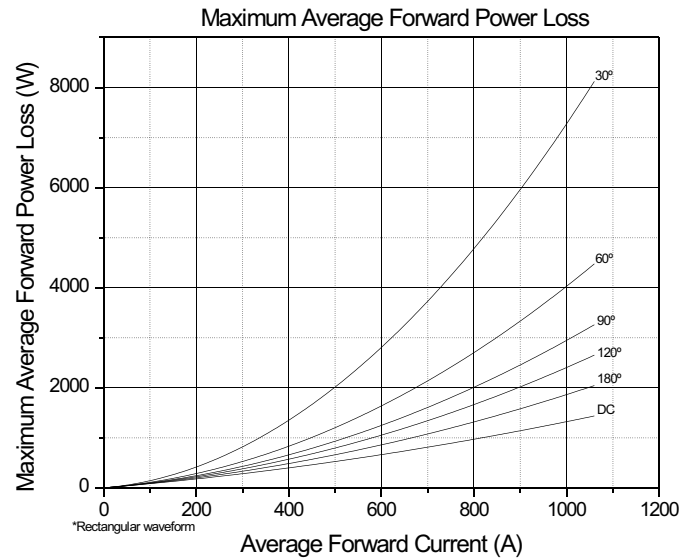


Fig. 4 - On-State Power Loss Characteristics

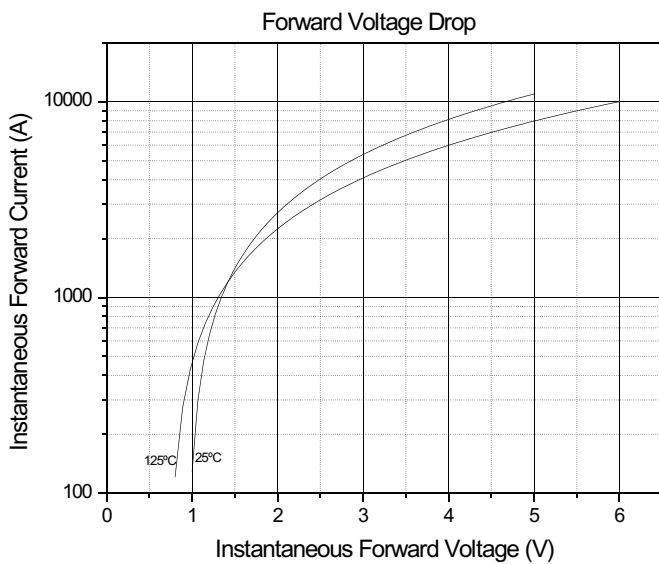


Fig. 5 - Forward Voltage Drop Characteristics

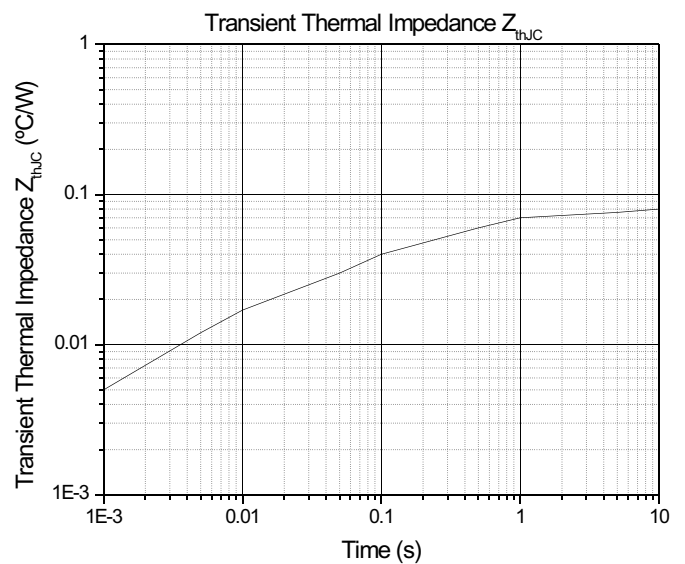


Fig. 6 - Transient Thermal Impedance Characteristics



A5A:670.XX

TO-200AA

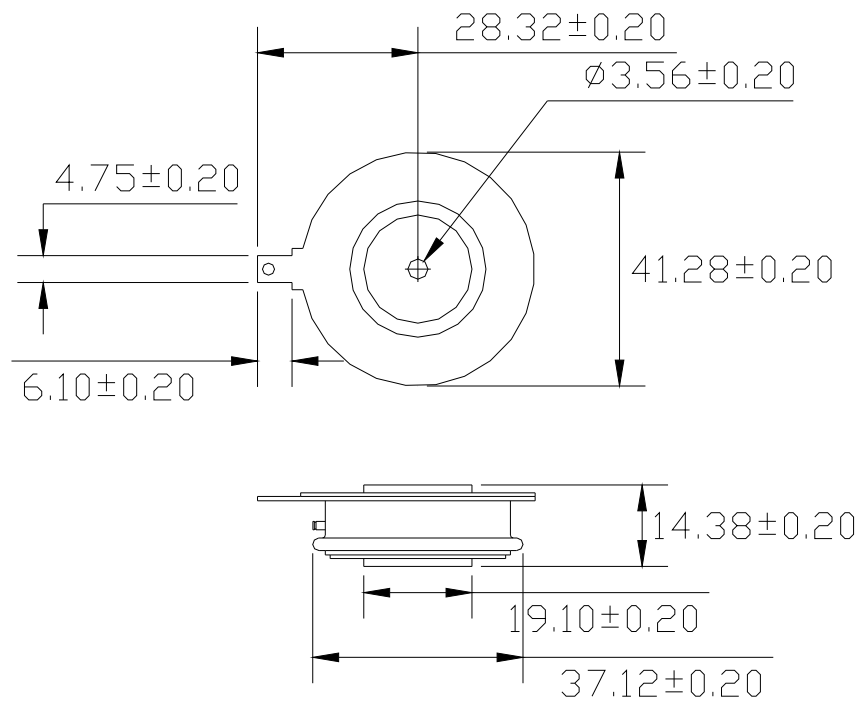


Fig. 7 - Outline Characteristics